

Technical Data Data Sheet N0080, Rev. E



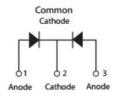
MBRF20100CT SCHOTTKY RECTIFIER



Features

- 175°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units	
Peak Repetitive Reverse Voltage	V_{RRM}	-	400	.,	
Working Peak Reverse Voltage	V _{RWM}		100	V	
DC Blocking Voltage	V_R				
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=133°C, rectangular	10(Per Leg)	A	
		wave form	20(Per Device)		
Peak One Cycle Non-Repetitive	I _{FSM}	8.3ms, Half Sine pulse	150	Α	
Surge Current(Per Leg)	IFSM	0.5ms, man Sine puise	130	_ ^	

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.76	0.80	V
		@ 10A, Pulse, T _J = 25 °C	0.85	0.90	V
	V_{F2}	@ 5A, Pulse, T _J = 125 °C	0.62	0.70	V
		@ 10A, Pulse, T _J = 125 °C	0.70	0.80	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.002	1.0	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	0.3	15	mA
Repetitive peak reverse current	I _{RRM}	tp = 2 μs square F= 1 kHz	-	1	Α
Junction Capacitance(Per Leg)	C⊤	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	200	300	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from	8.0	_	nH
		package body	0.0		
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs
RSM Isolation Voltage	V _{ISO}	Clip mounting, the epoxy body away	-	4500	V
(t = 1.0 second, R. H. < =30%,		from the heatsink edge by more than			
T _A = 25 °C)		0.110" along the lead direction.			
·		Clip mounting, the epoxy body is inside	-	3500	
		the heatsink.			

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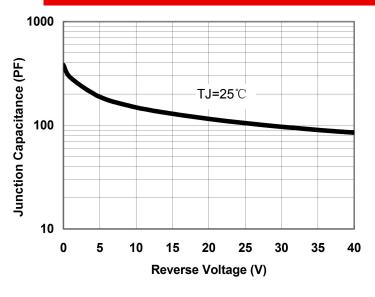


Technical Data Data Sheet N0080, Rev. E Screw mounting, the epoxy body is inside the heatsink. 1500

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R _{θJC}	DC operation	4.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

Ratings and Characteristics Curves



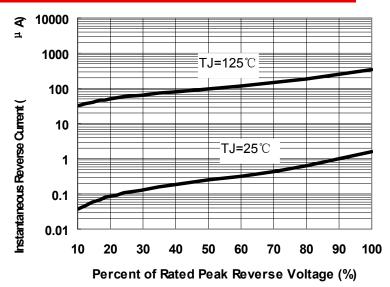


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

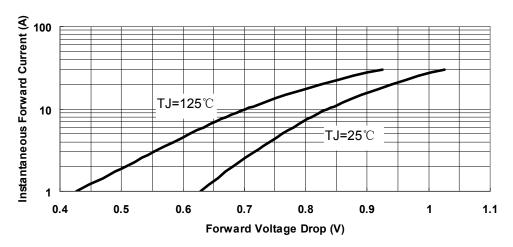


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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^{*} Pulse width < 300 µs, duty cycle < 2%

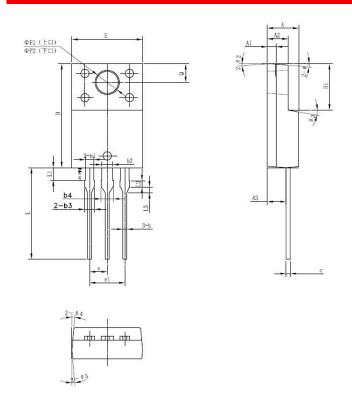


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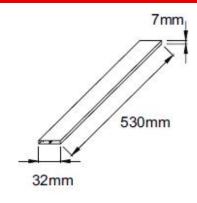


Mechanical Dimensions ITO-220AB

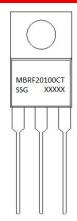


SYMBOL	Millimeters				
STWIBOL	MIN.	TYP.	MAX.		
Α	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
С	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ФР1(上□)	3.30	3.50	3.70		
ΦP2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

MBR = Device Type = Package type = Forward Current (20A) 20 = Reverse Voltage (100V) 100 = Configuration CT SSG

= SSG = Year WW = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
MBRF20100CT	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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